Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
0.270 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.105 inches	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
Do-7	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
200.0 reverse voltage, peak	
Current Rating Per Characteristic:	
100.00 milliamperes source cutoff current preset	
Power Rating Per Characteristic:	
200.0 milliwatts small-signal input power, common-collector absolute	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius ambient air	
Test Data Document:	
81413-226387 drawing (this is the basic governing drawing, such as a contractor drawing, original	equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing	g drawing)
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	

Unit Of Measure:

Demilitarization:

No

Fiig:

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